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N-Channel SuperFET[®] II FRFET[®] MOSFET

650 V, 24 A, 150 m Ω

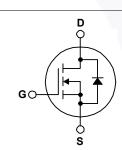
Features

- 700 V @ T_J = 150°C
- Typ. R_{DS(on)} = 133 mΩ
- Ultra Low Gate Charge (Typ. Q_g = 72 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 361 pF)
- 100% Avalanche Tested
- RoHS Compliant

Applications

- LCD / LED / PDP TV Telecom / Server Power Supplies
- Solar Inverter
 AC DC Power Supply





SuperFET[®] II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing

charge balance technology for outstanding low on-resistance

and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching perfor-

mance, dv/dt rate and higher avalanche energy. Consequently,

SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV

power, ATX power and industrial power applications. SuperFET II FRFET[®] MOSFET's optimized body diode reverse recovery

performance can remove additional component and improve

Description

system reliability.

Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

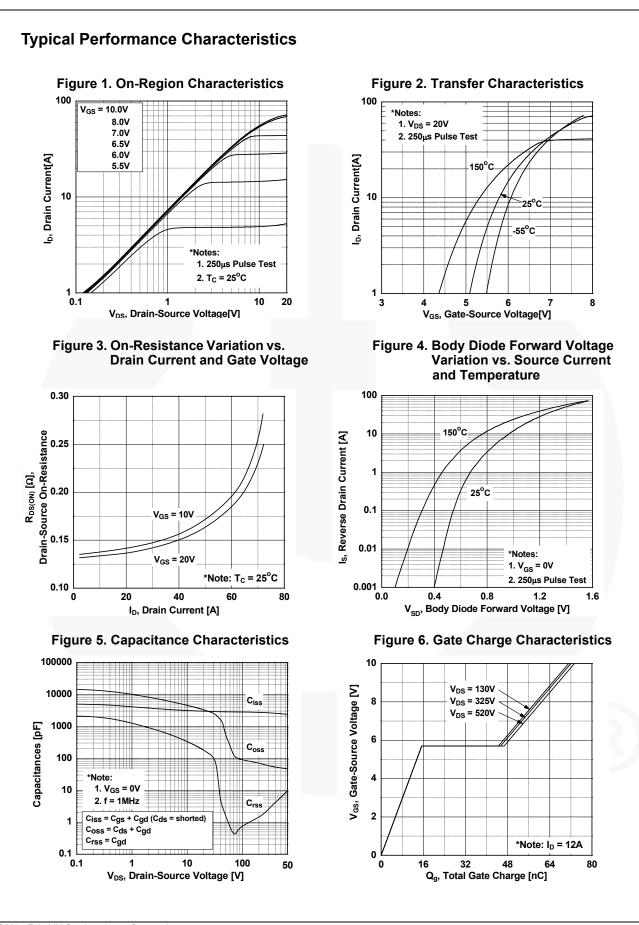
Symbol		FCH150N65F_F155	Unit			
V _{DSS}	Drain to Source Voltage				V	
V _{GSS}		- DC	- DC		V	
	Gate to Source Voltage	- AC	(f > 1 Hz)	±30	V	
ID	Drain Current	- Continuous (T _C = 25 ^o C)		24		
	Drain Current	- Continuous ($T_C = 100^{\circ}C$)		14.9	A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	72	А	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		663	mJ		
I _{AR}	Avalanche Current (Note 1)			4.7	А	
E _{AR}	Repetitive Avalanche Energy (Note 1)		2.98	mJ		
dv/dt	MOSFET dv/dt			100	Maa	
	Peak Diode Recovery dv/dt (Note 3)			50	V/ns	
P _D	Devues Dissinction	(T _C = 25 ^o C)		298	W	
	Power Dissipation	- Derate Above 25°C		2.38	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

Thermal Characteristics

Symbol	Parameter	FCH150N65F_F155	Unit	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max. 0.42			
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient, Max.		°C/W	

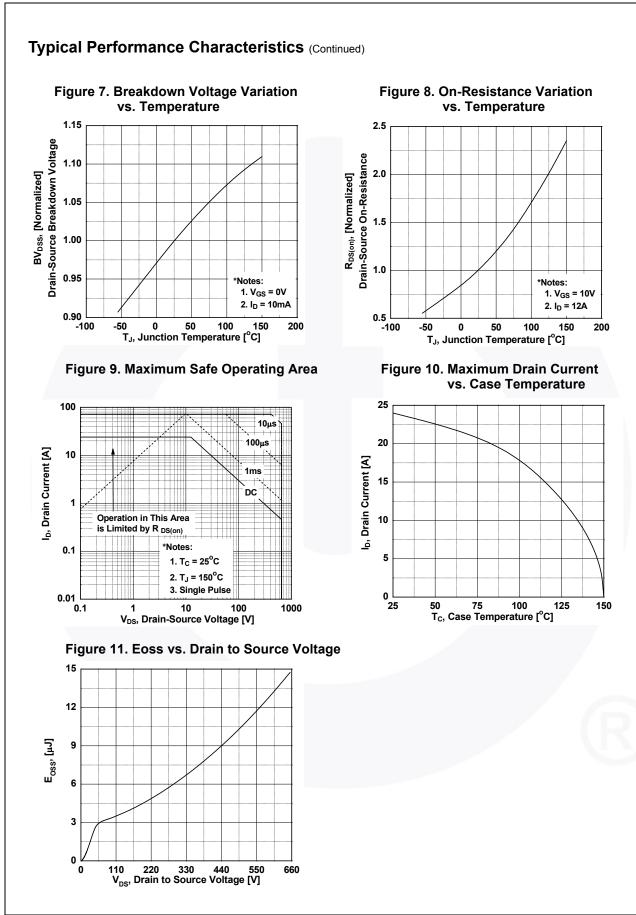
Part Number		Top Mark	Package	Packing Method	Reel Size	Тар	e Width	Qua	ntity	
FCH150N65	FCH150N65F_F155 FCH150N65F		TO-247 G03	Tube	N/A		N/A 30 uni		units	
Electrica	l Chara	acteristics T _C	= 25°C unless of	otherwise noted.						
Symbol	Parameter			Test Conditions		Min.	Тур.	Max.	Unit	
Off Charac	teristics	5								
	Drain to Source Breakdown Voltage		$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 10 \text{ mA}, \text{ T}_{J} = 25^{\circ}\text{C}$ $V_{GS} = 0 \text{ V}, \text{ I}_{D} = 10 \text{ mA}, \text{ T}_{J} = 150^{\circ}\text{C}$		650	-	-	V		
BV _{DSS}					700	700 -	-			
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient		$I_D = 10 \text{ mA}, \text{Referenced to } 25^{\circ}\text{C}$		-	0.72	-	V/ºC		
 	Zero Ga			V_{DS} = 650 V, V_{GS} = 0	V	-	-	10	10 μA	
IDSS	Zero Gate Voltage Drain Current		rent	$V_{DS} = 520 \text{ V}, V_{GS} = 0 \text{ V}, T_C = 125^{\circ}\text{C}$		-	86	-	μΑ	
I _{GSS}	Gate to	Body Leakage Curre	nt	V_{GS} = ±20 V, V_{DS} = 0	V	-	-	±100	nA	
On Charac	teristics	5								
V _{GS(th)}		reshold Voltage		$V_{GS} = V_{DS}, I_{D} = 2.4 \text{ mA}$		3	-	5	V	
R _{DS(on)}	Static Drain to Source On Resistance $V_{GS} = 10 \text{ V}, I_D = 12 \text{ A}$			-	133	150	mΩ			
9 _{FS}	Forward Transconductance			$V_{\rm DS} = 20 \text{ V}, \text{ I}_{\rm D} = 12 \text{ A}$		-	22	-	S	
Dynamic C	haracte	ristics			¥		1		1	
C _{iss}		Input Capacitance Output Capacitance			-	2810	3737	pF		
C _{oss}				$-V_{DS} = 100 V, V_{GS} = 0 V,$		-	91	121	pF	
C _{rss}	Reverse Transfer Capacitance		f = 1 MHz		-	0.77	-	pF		
C _{oss}	Output Capacitance			V _{DS} = 380 V, V _{GS} = 0 V, f = 1 MHz		-	54	-	pF	
C _{oss} eff.	Effective Output Capacitance		$V_{DS} = 0 V \text{ to } 400 V, V_{GS} = 0 V$		-	361	-	pF		
Q _{g(tot)}	Total Gate Charge at 10V $V_{DS} = 380 \text{ V}, \text{ I}_D = 12 \text{ A},$		A.	-	72	94	nC			
Q _{gs}	Gate to	Gate to Source Gate Charge V_{GS} = 10 V		,	-	15	-	nC		
Q _{gd}	Gate to			(Note 4)		-	31	-	nC	
EŠR	Equivale	nt Series Resistance	9	f = 1 MHz		-	0.69	-	Ω	
Switching	Charact	eristics								
t _{d(on)}		Delay Time			_	-	28	66	ns	
t _r		Rise Time		V_{DD} = 380 V, I _D = 12 A, V_{GS} = 10 V, R _g = 4.7 Ω		-	15	40	ns	
t _{d(off)}		Delay Time				-	73	156	ns	
t _f	Turn-Off Fall Time			(Note 4)		-	6	22	ns	
 Drain_Sou			~e	I	I					
	rce Diode Characteristics			le Forward Current		-	-	24	A	
I _{SM}	Maximum Pulsed Drain to Source Diode Fo					-	-	72	A	
V _{SD}	Drain to Source Diode Forward Voltage		$V_{GS} = 0 V$, $I_{SD} = 12 A$		-	-	1.2	V		
t _{rr}		Recovery Time	U -	$V_{GS} = 0 V, I_{SD} = 12 A,$ $V_{GS} = 0 V, I_{SD} = 12 A,$		-	123	-	ns	
Q _{rr}		Recovery Charge		dl _F /dt = 100 A/μs	,	-	597	-	nC	
Notes:		, J -		· ·			-	1	-	



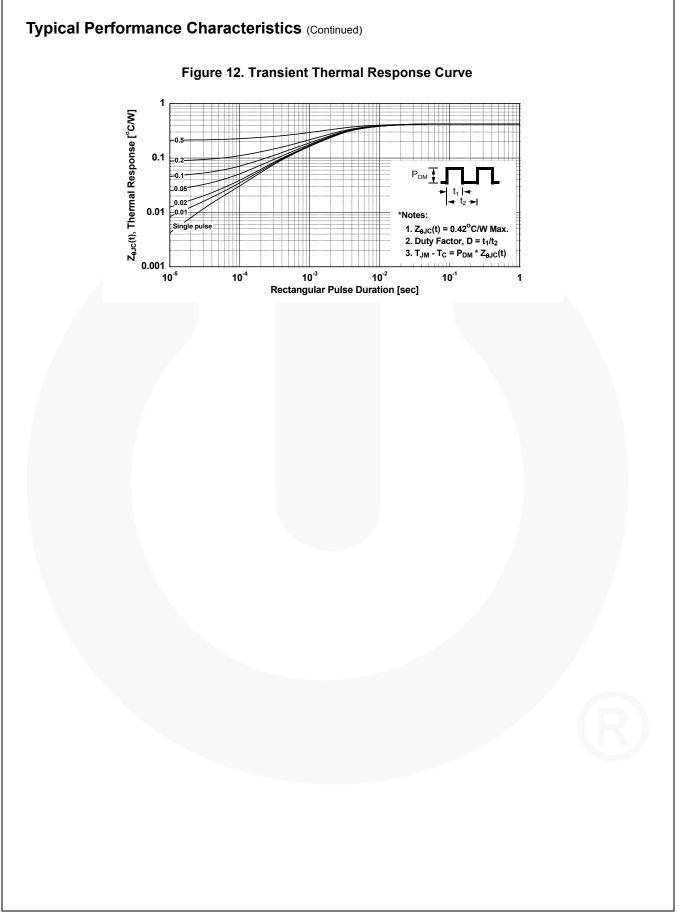


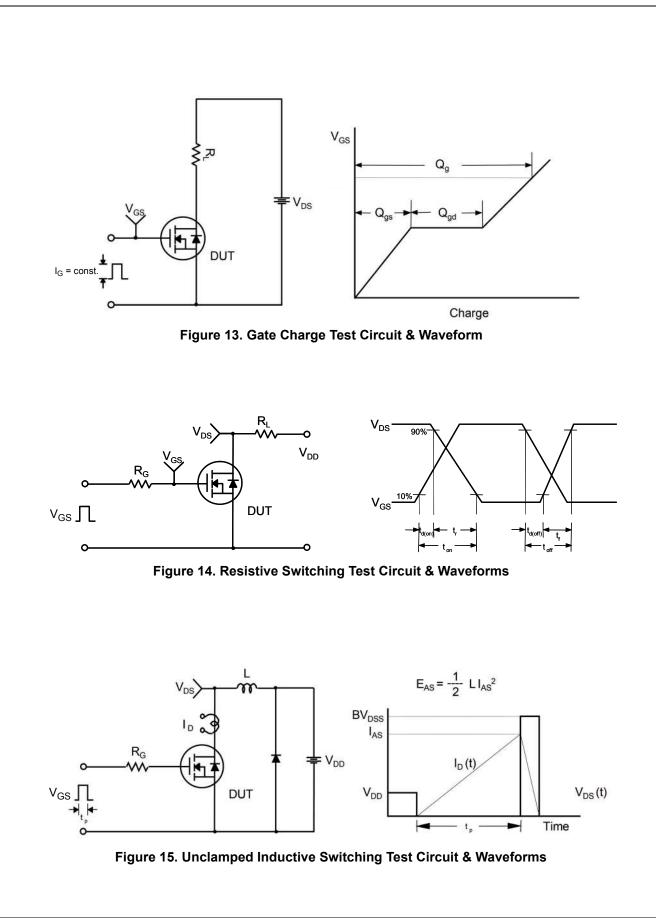
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FCH150N65F — N-Channel SuperFET[®] II FRFET[®] MOSFET

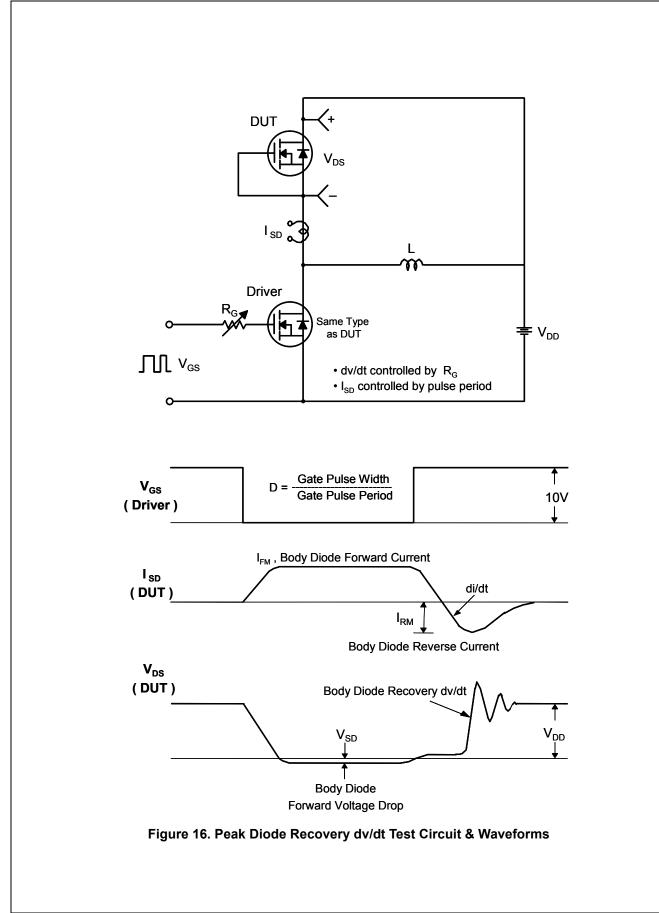


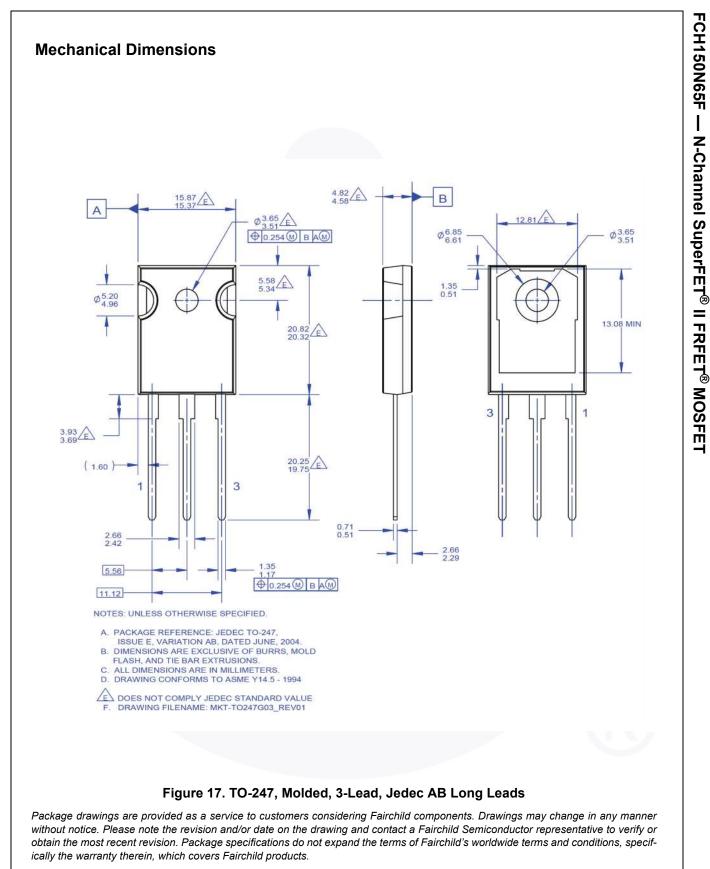
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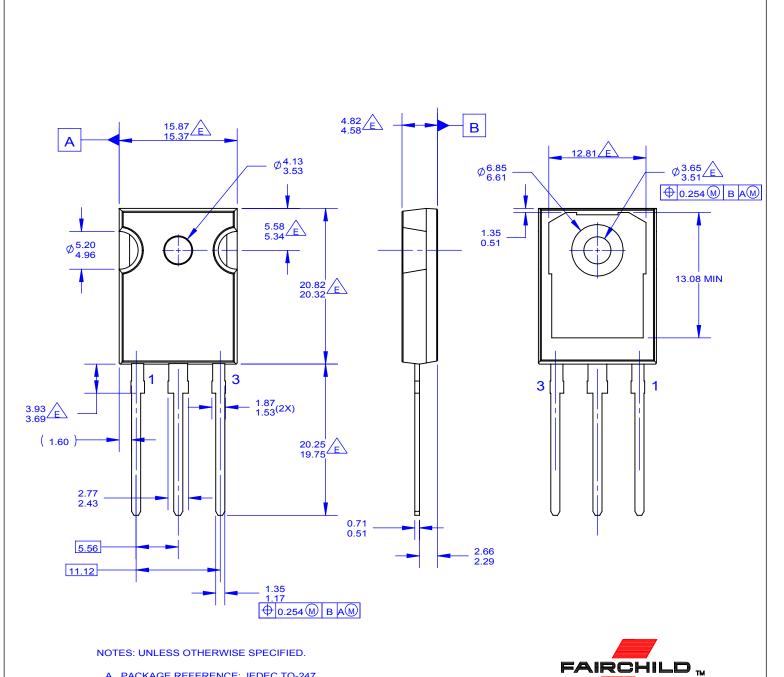
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